

Designer's Kit

v02.0710

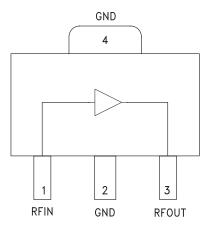
Typical Applications

Available

The HMC452ST89 / HMC452ST89E is ideal for applications requiring a high dynamic range amplifier:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- CATV/Cable Modem
- Fixed Wireless

Functional Diagram



InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

Features

Output IP3: +49 dBm 21 dB Gain @ 400 MHz 9 dB Gain @ 2100 MHz 50% PAE @ +31 dBm Pout +25 dBm CDMA2000 Channel Power @ -45 dBc ACP

Included in the HMC-DK002 Designer's Kit

General Description

The HMC452ST89 & HMC452ST89E are high dynamic range GaAs InGaP HBT 1 Watt MMIC power amplifiers operating from 0.4 to 2.2 GHz and packaged in industry standard SOT89 packages. Utilizing a minimum number of external components and a single +5V supply, the amplifier output IP3 can be optimized to +45 dBm at 0.4 GHz or +49 dBm at 2.1 GHz. The high output IP3 and PAE make the HMC452ST89 & HMC452ST89E ideal power amplifiers for Cellular/ PCS/3G and Fixed Wireless applications.

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		400 - 410)		450 - 49	6		810 - 960)	1	710 - 199	90	2	010 - 21	70	MHz
Gain	19	21		18	20		13.5	15.5		7	9.5		7	9		dB
Gain Variation Over Temperature		0.012	0.02		0.012	0.02		0.012	0.02		0.012	0.02		0.012	0.02	dB / °C
Input Return Loss		22			16			13			13			20		dB
Output Return Loss		11			11			14			15			15		dB
Output Power for 1dB Compression (P1dB)	27	30		27	30		27.5	30.5		28	31		28.5	31.5		dBm
Saturated Output Power (Psat)		30.5			30.5			31.5			31.5			32		dBm
Output Third Order Intercept (IP3) [2]	42	45		42	45		44	47		45	48		46	49		dBm
Noise Figure		6.5			7			6.5			6.5			6.5		dB
Supply Current (Icq)		510			510			510			510			510		mA

Electrical Specifications, $T_{A} = +25^{\circ}C$, $Vs = +5V^{[1]}$

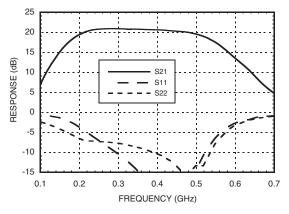
[1] Specifications and data reflect HMC452ST89 measured using the respective application circuits for each designated frequency band found herein. Contact the HMC Applications Group for assistance in optimizing performance for your application. [2] Two-tone input power of 0 dBm per tone, 1 MHz spacing.

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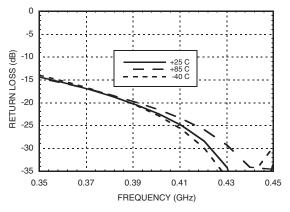




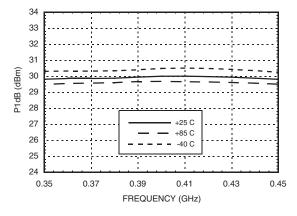
Broadband Gain & Return Loss @ 400 MHz



Input Return Loss vs. Temperature @ 400 MHz



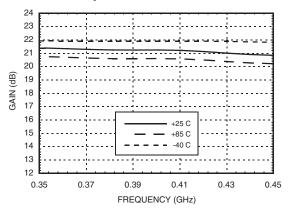
P1dB vs. Temperature @ 400 MHz



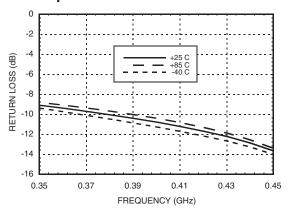
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

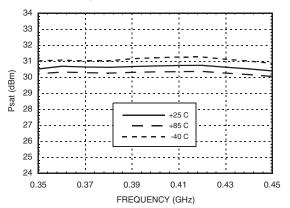
Gain vs. Temperature @ 400 MHz



Output Return Loss vs. Temperature @ 400 MHz



Psat vs. Temperature @ 400 MHz

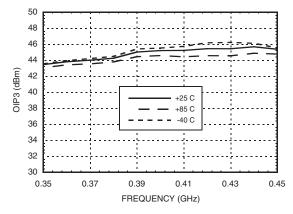


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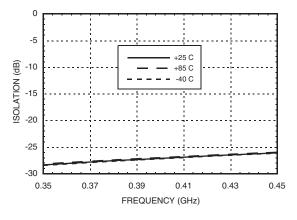




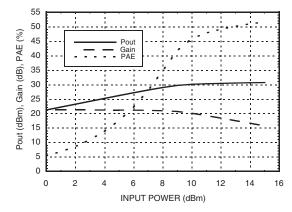
Output IP3 vs. Temperature @ 400 MHz



Reverse Isolation vs. Temperature @ 400 MHz

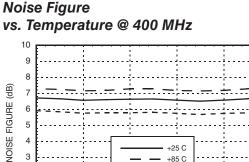


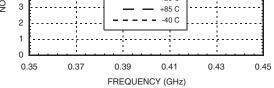
Power Compression @ 400 MHz



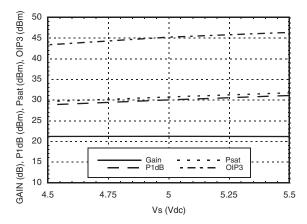
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

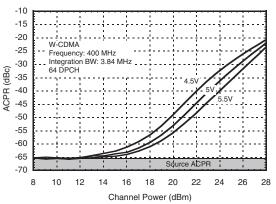




Gain, Power & IP3 vs. Supply Voltage @ 400 MHz



ACPR vs. Supply Voltage @ 400 MHz W-CDMA, 64 DPCH

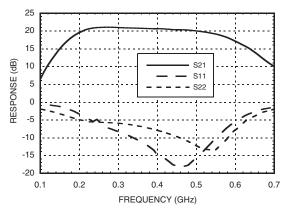


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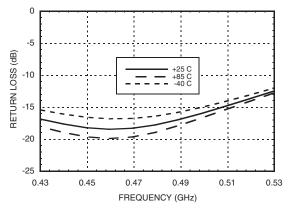




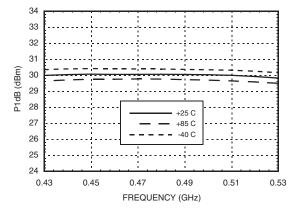
Broadband Gain & Return Loss @ 470 MHz



Input Return Loss vs. Temperature @ 470 MHz



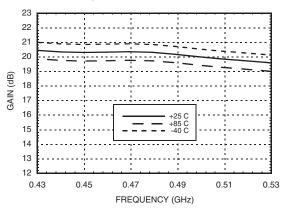
P1dB vs. Temperature @ 470 MHz



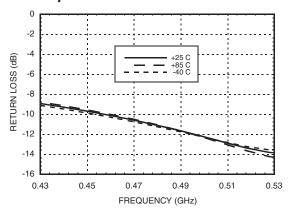
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

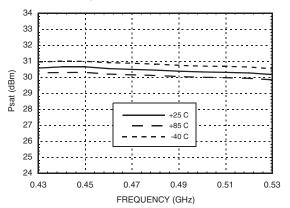
Gain vs. Temperature @ 470 MHz



Output Return Loss vs. Temperature @ 470 MHz



Psat vs. Temperature @ 470 MHz

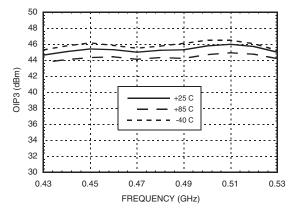


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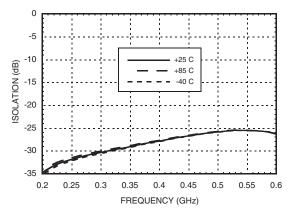




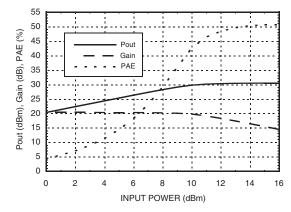
Output IP3 vs. Temperature @ 470 MHz



Reverse Isolation vs. Temperature @ 470 MHz

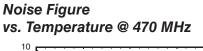


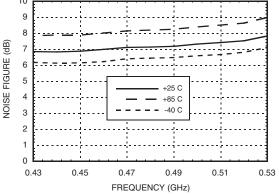
Power Compression @ 470 MHz



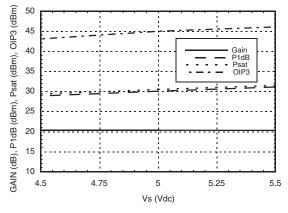
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

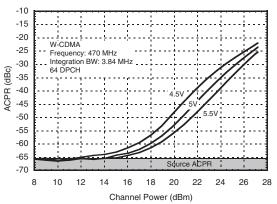




Gain, Power & IP3 vs. Supply Voltage @ 470 MHz



ACPR vs. Supply Voltage @ 470 MHz W-CDMA, 64 DPCH

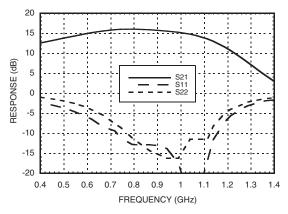


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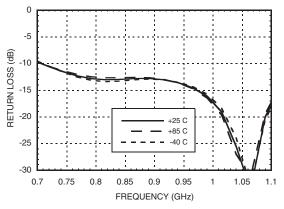




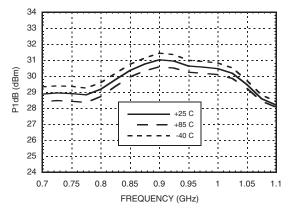
Broadband Gain & Return Loss @ 900 MHz



Input Return Loss vs. Temperature @ 900 MHz

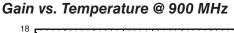


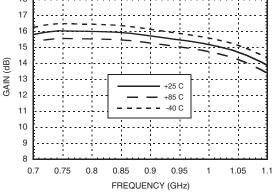
P1dB vs. Temperature @ 900 MHz



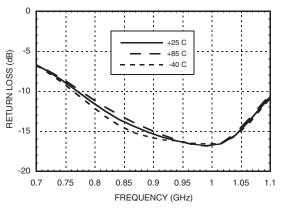
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

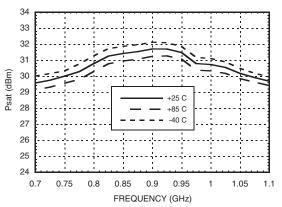




Output Return Loss vs. Temperature @ 900 MHz



Psat vs. Temperature @ 900 MHz



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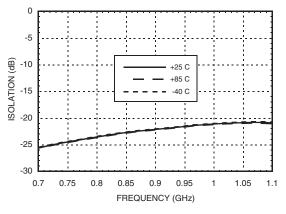




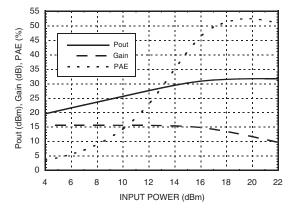
50 48 46 44 OIP3 (dBm) 42 40 38 +25 C +85 C -40 C 36 34 32 30 0.75 0.8 0.85 0.9 0.95 1.05 1.1 FREQUENCY (GHz)

Output IP3 vs. Temperature @ 900 MHz

Reverse Isolation vs. Temperature @ 900 MHz

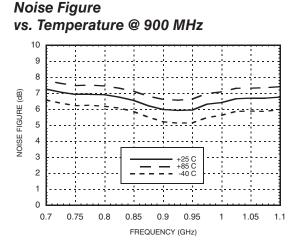


Power Compression @ 900 MHz

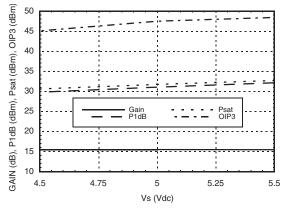


HMC452ST89 / 452ST89E

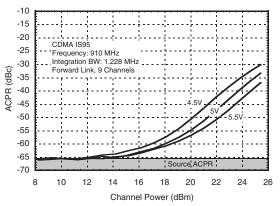
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 900 MHz



ACPR vs. Supply Voltage @ 910 MHz CDMA IS95, 9 Channels Forward

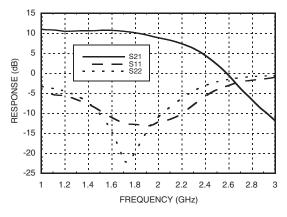


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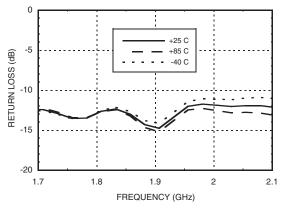




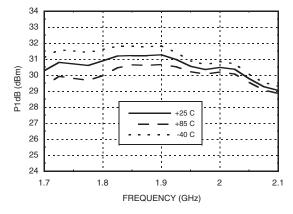
Broadband Gain & Return Loss @ 1900 MHz



Input Return Loss vs. Temperature @ 1900 MHz

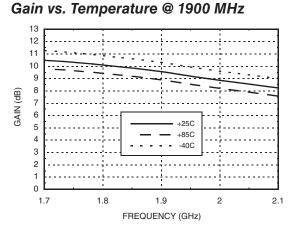


P1dB vs. Temperature @ 1900 MHz

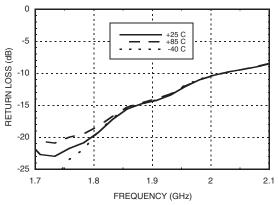


HMC452ST89 / 452ST89E

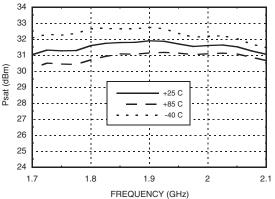
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 1900 MHz



Psat vs. Temperature @ 1900 MHz

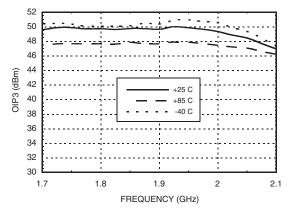


2.1

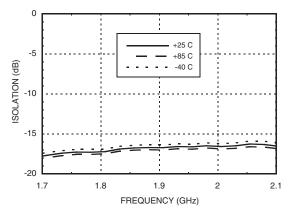




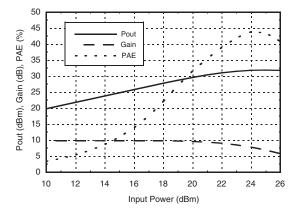
Output IP3 vs. Temperature @ 1900 MHz



Reverse Isolation vs. Temperature @ 1900 MHz

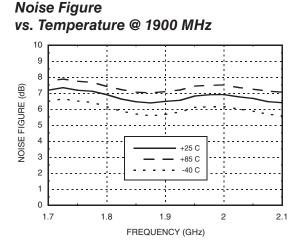


Power Compression @ 1900 MHz

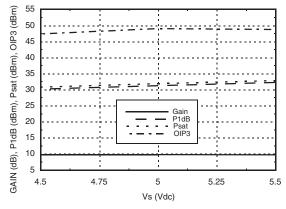


HMC452ST89 / 452ST89E

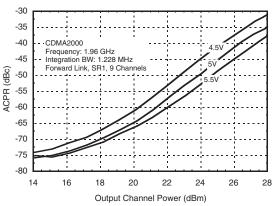
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 1900 MHz



ACPR vs. Supply Voltage @ 1960 MHz CDMA 2000, 9 Channels Forward

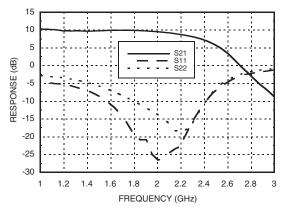


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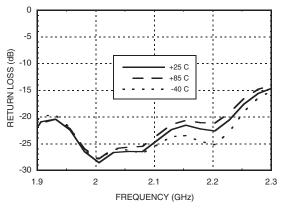




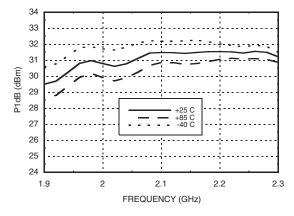
Broadband Gain & Return Loss @ 2100 MHz



Input Return Loss vs. Temperature @ 2100 MHz

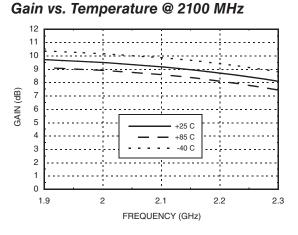


P1dB vs. Temperature @ 2100 MHz

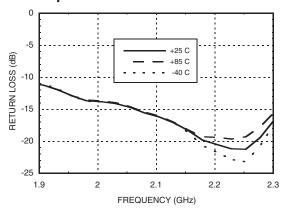


HMC452ST89 / 452ST89E

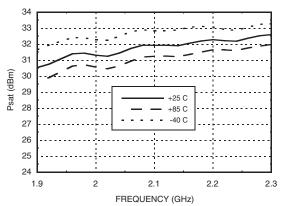
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 2100 MHz



Psat vs. Temperature @ 2100 MHz

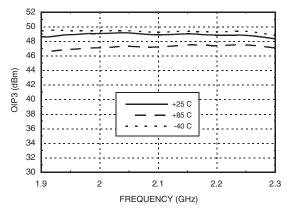


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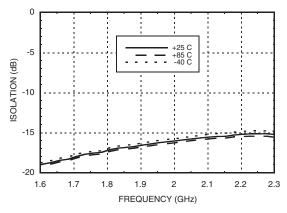




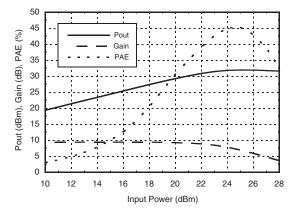
Output IP3 vs. Temperature @ 2100 MHz



Reverse Isolation vs. Temperature @ 2100 MHz

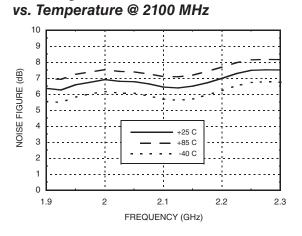


Power Compression @ 2100 MHz



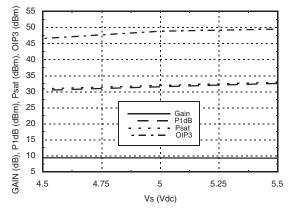
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

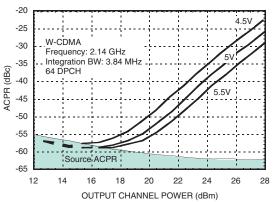


Gain, Power & IP3 vs. Supply Voltage @ 2100 MHz

Noise Figure



ACPR vs. Supply Voltage @ 2140 MHz W-CDMA, 64 DPCH

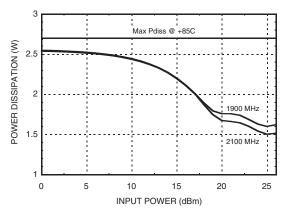


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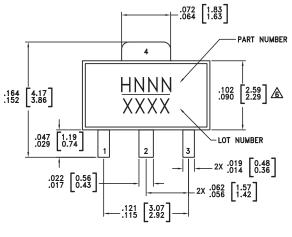


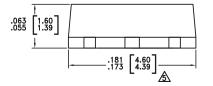


Power Dissipation



Outline Drawing





HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6.0 Vdc	
RF Input Power (RFIN)(Vs +5Vdc)	+31 dBm	
Junction Temperature	150 °C	
Continuous Pdiss (T = 85 °C) (derate 41.5 mW/°C above 85 °C)	2.7 W	
Thermal Resistance (junction to ground paddle)	24.1 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class 1A	



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

EXPOSED GROUND PADDLE

NOTES:

1. PACKAGE BODY MATERIAL:

MOLDING COMPOUND MP-180S OR EQUIVALENT.

2. LEAD MATERIAL: Cu w/ Ag SPOT PLATING.

3. LEAD PLATING: 100% MATTE TIN.

4. DIMENSIONS ARE IN INCHES [MILLIMETERS]

ADIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.

7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC452ST89	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H452 XXXX
HMC452ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H452 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 $^\circ\text{C}$

[3] 4-Digit lot number XXXX

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HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

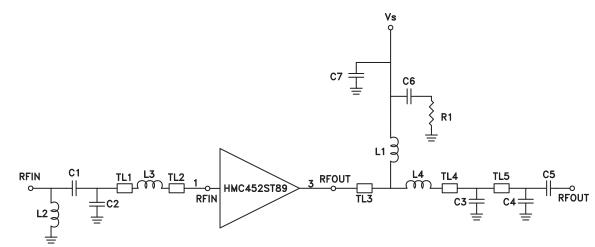


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. Off chip matching components are required. See Application Circuit herein.	RFINO
3	RFOUT	RF output and DC Bias input for the output amplifier stage. Off chip matching components are required. See Application Circuit herein.	=
2, 4	GND	These pins & package bottom must be connected to RF/DC ground.	GND =

400 MHz Application Circuit

This circuit was used to specify the performance for 400-410 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3	TL4	TL5
Impedance	50 Ohm				
Physical Length	0.09"	0.08"	0.17"	0.04"	0.25"
Electrical Length 2° 2° 4° 1° 6°					
PCB Material: 10 mil Rogers 4350, Er = 3.48					

Recommended C	Recommended Component Values			
C1	12 pF			
C2	15 pF			
C3, C4	6.8 pF			
C5	39 pF			
C6	100 pF			
C7	2.2 µF			
L1	47 nH			
L2	40 nH			
L3	4.3 nH			
L4	5.1 nH			
R1	5.1 Ohm			

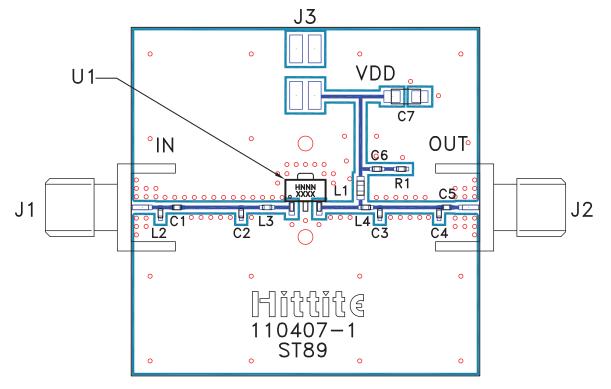
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InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



400 MHz Evaluation PCB



List of Materials for Evaluation PCB 110409-400 [1]

v02.0710

Item	Description	
J1 - J2	PCB Mount SMA Connector	
J3	2 mm DC Header	
C1	12 pF Capacitor, 0402 Pkg.	
C2	15 pF Capacitor, 0402 Pkg.	
C3, C4	6.8 pF Capacitor, 0402 Pkg.	
C5	39 pF Capacitor, 0402 Pkg.	
C6	100 pF Capacitor, 0402 Pkg.	
C7	2.2 µF Capacitor, Tantalum	
L1	47 nH Inductor, 0603 Pkg.	
L2	40 nH Inductor, 0402 Pkg.	
L3	4.3 nH Inductor, 0402 Pkg.	
L4	5.1 nH Inductor, 0402 Pkg.	
R1	5.1 Ohm Resistor, 0402 Pkg.	
U1	HMC452ST89 / HMC452ST89E Linear Amp	
PCB [2]	110407 Evaluation PCB, 10 mils	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

amplifiers - Linear & Power - SMT 😡



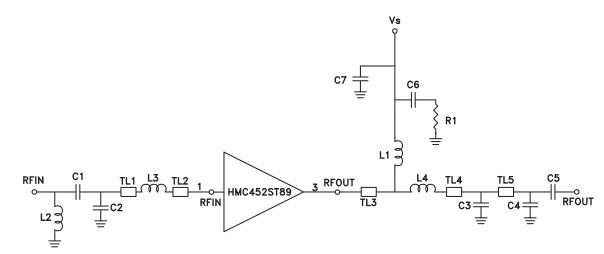
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



470 MHz Application Circuit

This circuit was used to specify the performance for 450-496 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3	TL4	TL5
Impedance	50 Ohm				
Physical Length	0.09"	0.08"	0.17"	0.04"	0.25"
Electrical Length 2.5° 2° 5° 1° 7°					
PCB Material: 10 mil Rogers 4350, Er = 3.48					

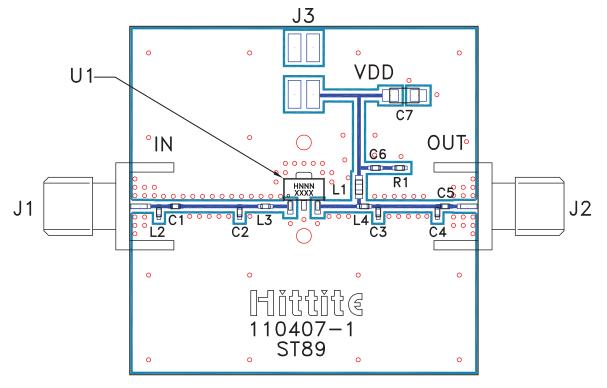
Recommended C	omponent Values
C1, C2	12 pF
C3	6.8 pF
C4	5.6 pF
C5	39 pF
C6	100 pF
C7	2.2 μF
L1	47 nH
L2	40 nH
L3	4.7 nH
L4	3.9 nH
R1	5.1 Ohm



InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



470 MHz Evaluation PCB



v02.0710

List of Materials for Evaluation PCB 110416-470 [1]

Item	Description	
J1 - J2	PCB Mount SMA Connector	
J3	2 mm DC Header	
C1, C2	12 pF Capacitor, 0402 Pkg.	
C3	6.8 pF Capacitor, 0402 Pkg.	
C4	5.6 pF Capacitor, 0402 Pkg.	
C5	39 pF Capacitor, 0402 Pkg.	
C6	100 pF Capacitor, 0402 Pkg.	
C7	2.2 µF Capacitor, Tantalum	
L1	47 nH Inductor, 0603 Pkg.	
L2	40 nH Inductor, 0402 Pkg.	
L3	4.7 nH Inductor, 0402 Pkg.	
L4	3.9 nH Inductor, 0402 Pkg.	
R1	5.1 Ohm Resistor, 0402 Pkg.	
U1	HMC452ST89 / HMC452ST89E Linear Amp	
PCB [2]	110407 Evaluation PCB, 10 mils	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



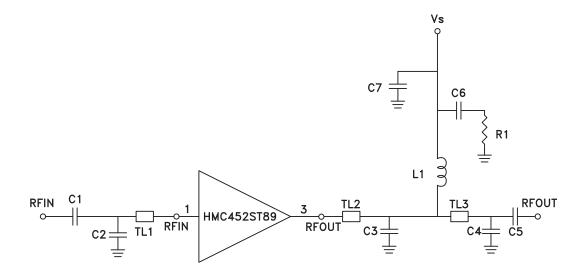
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



900 MHz Application Circuit

This circuit was used to specify the performance for 810-960 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.

v02.0710



Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3	
Impedance	50 Ohm			
Physical Length	0.21"	0.13"	0.38"	
Electrical Length 11° 7° 20°				
PCB Material: 10 mil Rogers 4350, Er = 3.48				

Recommended C	Recommended Component Values				
C1	27 pF				
C2	6.8 pF				
C3	2.2 pF				
C4	4.7 pF				
C5	5.6 pF				
C6	100 pF				
C7	2.2 µF				
L1	20 nH				
R1	5.1 Ohm				

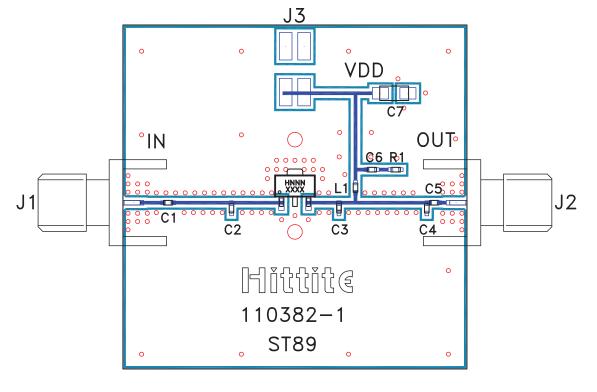
9 - 140



InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



900 MHz Evaluation PCB



v02.0710

List of Materials for Evaluation PCB 110384-900 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	27 pF Capacitor, 0402 Pkg.
C2	6.8 pF Capacitor, 0402 Pkg.
C3	2.2 pF Capacitor, 0402 Pkg.
C4	4.7 pF Capacitor, 0402 Pkg.
C5	5.6 pF Capacitor, 0402 Pkg.
C6	100 pF Capacitor, 0402 Pkg.
C7	2.2 µF Capacitor, Tantalum
L1	20 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB [2]	110382 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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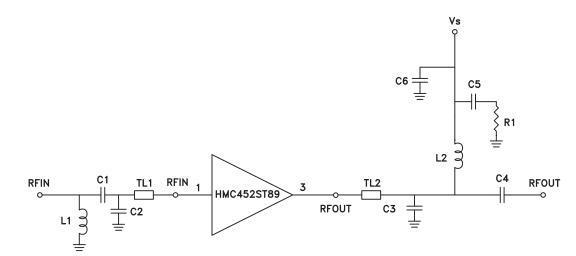
InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



1900 MHz Application Circuit

This circuit was used to specify the performance for 1710-1990 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.

v02.0710



Note: C2 should be placed as close to pins as possible.

	TL1	TL2
Impedance	50 Ohm	50 Ohm
Physical Length	0.04"	0.10"
Electrical Length	4°	11°
PCB Material: 10 mil Rogers 4350, Er = 3.48		

Recommended Component Values		
C1	3 pF	
C2	2 pF	
C3	3.3 pF	
C4	15 pF	
C5	100 pF	
C6	2.2 μF	
L1	10 nH	
L2	12 nH	
R1	5.1 Ohm	

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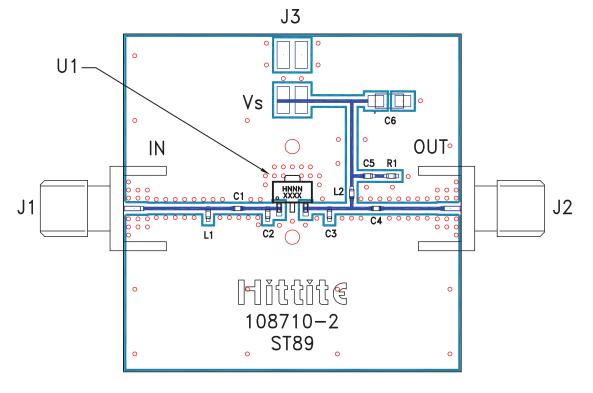


InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



1900 MHz Evaluation PCB

v02.0710



List of Materials for Evaluation PCB 108712-1900 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	3 pF Capacitor, 0402 Pkg.
C2	2 pF Capacitor, 0402 Pkg.
C3	3.3 pF Capacitor, 0402 Pkg.
C4	15 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
C6	2.2 µF Capacitor, Tantalum
L1	10 nH Inductor, 0402 Pkg.
L2	12 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB [2]	108710 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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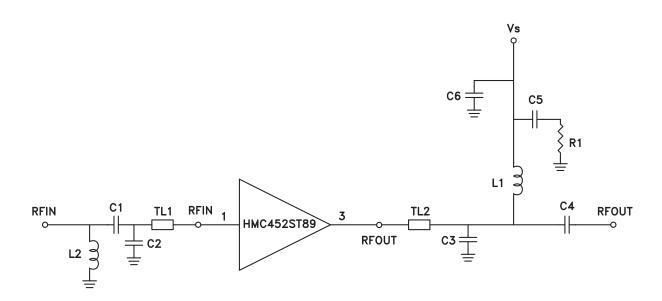
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



2100 MHz Application Circuit

This circuit was used to specify the performance for 2010-2170 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



	TL1	TL2
Impedance	50 Ohm	50 Ohm
Physical Length	0.04"	0.04"
Electrical Length	5°	5°
PCB Material: 10 mil Rogers 4350. Er = 3.48		

Recommended Component Values		
C1	3 pF	
C2	2 pF	
C3	3.3 pF	
C4	15 pF	
C5	100 pF	
C6	2.2 μF	
L1	12 nH	
L2	10 nH	
R1	5.1 Ohm	